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# Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

# **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	216
Number of Logic Elements/Cells	1728
Total RAM Bits	24576
Number of I/O	147
Number of Gates	119000
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 85°C (TA)
Package / Case	208-BFQFP
Supplier Device Package	208-PQFP (28x28)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epf10k30eqi208-2n

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Table 2. FLEX 10KE Device Features							
Feature	EPF10K100E (2)	EPF10K130E	EPF10K200E EPF10K200S				
Typical gates (1)	100,000	130,000	200,000				
Maximum system gates	257,000	342,000	513,000				
Logic elements (LEs)	4,992	6,656	9,984				
EABs	12	16	24				
Total RAM bits	49,152	65,536	98,304				
Maximum user I/O pins	338	413	470				

#### Note to tables:

- (1) The embedded IEEE Std. 1149.1 JTAG circuitry adds up to 31,250 gates in addition to the listed typical or maximum system gates.
- (2) New EPF10K100B designs should use EPF10K100E devices.

# ...and More Features

- Fabricated on an advanced process and operate with a 2.5-V internal supply voltage
- In-circuit reconfigurability (ICR) via external configuration devices, intelligent controller, or JTAG port
- ClockLock<sup>TM</sup> and ClockBoost<sup>TM</sup> options for reduced clock delay/skew and clock multiplication
- Built-in low-skew clock distribution trees
- 100% functional testing of all devices; test vectors or scan chains are not required
- Pull-up on I/O pins before and during configuration

# ■ Flexible interconnect

- FastTrack® Interconnect continuous routing structure for fast, predictable interconnect delays
- Dedicated carry chain that implements arithmetic functions such as fast adders, counters, and comparators (automatically used by software tools and megafunctions)
- Dedicated cascade chain that implements high-speed, high-fan-in logic functions (automatically used by software tools and megafunctions)
- Tri-state emulation that implements internal tri-state buses
- Up to six global clock signals and four global clear signals

### ■ Powerful I/O pins

- Individual tri-state output enable control for each pin
- Open-drain option on each I/O pin
- Programmable output slew-rate control to reduce switching noise
- Clamp to V<sub>CCIO</sub> user-selectable on a pin-by-pin basis
- Supports hot-socketing

- Software design support and automatic place-and-route provided by Altera's development systems for Windows-based PCs and Sun SPARCstation, and HP 9000 Series 700/800
- Flexible package options
  - Available in a variety of packages with 144 to 672 pins, including the innovative FineLine BGA<sup>TM</sup> packages (see Tables 3 and 4)
  - SameFrame<sup>™</sup> pin-out compatibility between FLEX 10KA and FLEX 10KE devices across a range of device densities and pin counts
- Additional design entry and simulation support provided by EDIF 2 0 0 and 3 0 0 netlist files, library of parameterized modules (LPM), DesignWare components, Verilog HDL, VHDL, and other interfaces to popular EDA tools from manufacturers such as Cadence, Exemplar Logic, Mentor Graphics, OrCAD, Synopsys, Synplicity, VeriBest, and Viewlogic

Table 3. FLEX 10KE Package Options & I/O Pin Count Notes (1), (2)									
Device	144-Pin TQFP	208-Pin PQFP	240-Pin PQFP RQFP	256-Pin FineLine BGA	356-Pin BGA	484-Pin FineLine BGA	599-Pin PGA	600-Pin BGA	672-Pin FineLine BGA
EPF10K30E	102	147		176		220			220 (3)
EPF10K50E	102	147	189	191		254			254 (3)
EPF10K50S	102	147	189	191	220	254			254 (3)
EPF10K100E		147	189	191	274	338			338 (3)
EPF10K130E			186		274	369		424	413
EPF10K200E							470	470	470
EPF10K200S			182		274	369	470	470	470

#### Notes:

- (1) FLEX 10KE device package types include thin quad flat pack (TQFP), plastic quad flat pack (PQFP), power quad flat pack (RQFP), pin-grid array (PGA), and ball-grid array (BGA) packages.
- (2) Devices in the same package are pin-compatible, although some devices have more I/O pins than others. When planning device migration, use the I/O pins that are common to all devices.
- (3) This option is supported with a 484-pin FineLine BGA package. By using SameFrame pin migration, all FineLine BGA packages are pin-compatible. For example, a board can be designed to support 256-pin, 484-pin, and 672-pin FineLine BGA packages. The Altera software automatically avoids conflicting pins when future migration is set.

The EAB can also be used for bidirectional, dual-port memory applications where two ports read or write simultaneously. To implement this type of dual-port memory, two EABs are used to support two simultaneous read or writes.

Alternatively, one clock and clock enable can be used to control the input registers of the EAB, while a different clock and clock enable control the output registers (see Figure 2).

Dedicated Inputs & Global Signals **Dedicated Clocks** Row Interconnect RAM/ROM 256 × 16 512 × 8 data[] 2.048 × 2 ENA FNA rdaddress[] EAB Local ENA Interconnect (2) wraddress[] 4, 8, 16, 32 FΝΔ rden wren outclocken Write Enable inclocken Multiplexers allow read address and read inclock enable registers to be clocked by inclock or outclock outclock signals.

Figure 2. FLEX 10KE Device in Dual-Port RAM Mode Notes (1)

# Notes:

(1) All registers can be asynchronously cleared by EAB local interconnect signals, global signals, or the chip-wide reset.

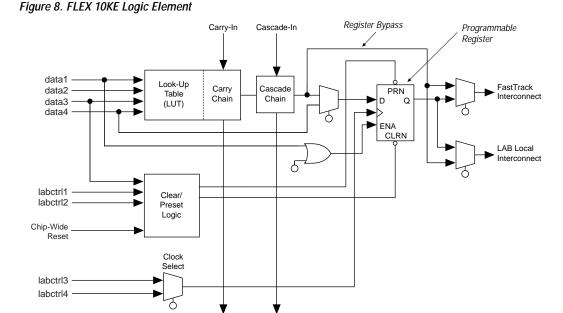
Column Interconnect

(2) EPF10K30E and EPF10K50E devices have 88 EAB local interconnect channels; EPF10K100E, EPF10K130E, and EPF10K200E devices have 104 EAB local interconnect channels.

Each LAB provides four control signals with programmable inversion that can be used in all eight LEs. Two of these signals can be used as clocks, the other two can be used for clear/preset control. The LAB clocks can be driven by the dedicated clock input pins, global signals, I/O signals, or internal signals via the LAB local interconnect. The LAB preset and clear control signals can be driven by the global signals, I/O signals, or internal signals via the LAB local interconnect. The global control signals are typically used for global clock, clear, or preset signals because they provide asynchronous control with very low skew across the device. If logic is required on a control signal, it can be generated in one or more LE in any LAB and driven into the local interconnect of the target LAB. In addition, the global control signals can be generated from LE outputs.

# Logic Element

The LE, the smallest unit of logic in the FLEX 10KE architecture, has a compact size that provides efficient logic utilization. Each LE contains a four-input LUT, which is a function generator that can quickly compute any function of four variables. In addition, each LE contains a programmable flipflop with a synchronous clock enable, a carry chain, and a cascade chain. Each LE drives both the local and the FastTrack Interconnect routing structure (see Figure 8).



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Cascade-Out

Carry-Out

Figure 9 shows how an n-bit full adder can be implemented in n+1 LEs with the carry chain. One portion of the LUT generates the sum of two bits using the input signals and the carry-in signal; the sum is routed to the output of the LE. The register can be bypassed for simple adders or used for an accumulator function. Another portion of the LUT and the carry chain logic generates the carry-out signal, which is routed directly to the carry-in signal of the next-higher-order bit. The final carry-out signal is routed to an LE, where it can be used as a general-purpose signal.

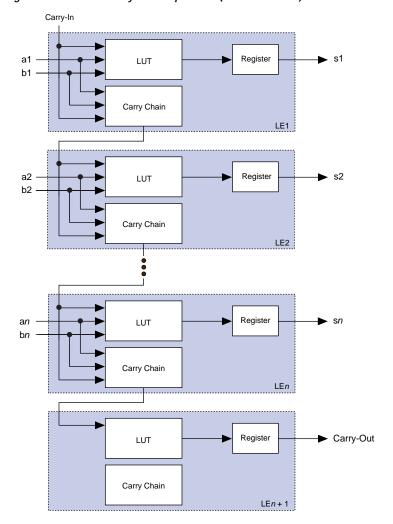


Figure 9. FLEX 10KE Carry Chain Operation (n-Bit Full Adder)

# LE Operating Modes

The FLEX 10KE LE can operate in the following four modes:

- Normal mode
- Arithmetic mode
- Up/down counter mode
- Clearable counter mode

Each of these modes uses LE resources differently. In each mode, seven available inputs to the LE—the four data inputs from the LAB local interconnect, the feedback from the programmable register, and the carry-in and cascade-in from the previous LE—are directed to different destinations to implement the desired logic function. Three inputs to the LE provide clock, clear, and preset control for the register. The Altera software, in conjunction with parameterized functions such as LPM and DesignWare functions, automatically chooses the appropriate mode for common functions such as counters, adders, and multipliers. If required, the designer can also create special-purpose functions that use a specific LE operating mode for optimal performance.

The architecture provides a synchronous clock enable to the register in all four modes. The Altera software can set DATA1 to enable the register synchronously, providing easy implementation of fully synchronous designs.

#### Clearable Counter Mode

The clearable counter mode is similar to the up/down counter mode, but supports a synchronous clear instead of the up/down control. The clear function is substituted for the cascade-in signal in the up/down counter mode. Use 2 three-input LUTs: one generates the counter data, and the other generates the fast carry bit. Synchronous loading is provided by a 2-to-1 multiplexer. The output of this multiplexer is ANDed with a synchronous clear signal.

## Internal Tri-State Emulation

Internal tri-state emulation provides internal tri-states without the limitations of a physical tri-state bus. In a physical tri-state bus, the tri-state buffers' output enable (OE) signals select which signal drives the bus. However, if multiple OE signals are active, contending signals can be driven onto the bus. Conversely, if no OE signals are active, the bus will float. Internal tri-state emulation resolves contending tri-state buffers to a low value and floating buses to a high value, thereby eliminating these problems. The Altera software automatically implements tri-state bus functionality with a multiplexer.

# Clear & Preset Logic Control

Logic for the programmable register's clear and preset functions is controlled by the DATA3, LABCTRL1, and LABCTRL2 inputs to the LE. The clear and preset control structure of the LE asynchronously loads signals into a register. Either LABCTRL1 or LABCTRL2 can control the asynchronous clear. Alternatively, the register can be set up so that LABCTRL1 implements an asynchronous load. The data to be loaded is driven to DATA3; when LABCTRL1 is asserted, DATA3 is loaded into the register.

During compilation, the Altera Compiler automatically selects the best control signal implementation. Because the clear and preset functions are active-low, the Compiler automatically assigns a logic high to an unused clear or preset.

The clear and preset logic is implemented in one of the following six modes chosen during design entry:

- Asynchronous clear
- Asynchronous preset
- Asynchronous clear and preset
- Asynchronous load with clear
- Asynchronous load with preset
- Asynchronous load without clear or preset

LE 1

LE 2

LE 8

To LAB Local Interconnect

Row Channels

At each intersection, six row channels can drive column channels.

Each LE can drive two row channels.

Each LE can switch interconnect access

with an LE in the adjacent LAB.

From Adjacent LAB To Adjacent LAB

Figure 13. FLEX 10KE LAB Connections to Row & Column Interconnect

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To Other Rows

For improved routing, the row interconnect consists of a combination of full-length and half-length channels. The full-length channels connect to all LABs in a row; the half-length channels connect to the LABs in half of the row. The EAB can be driven by the half-length channels in the left half of the row and by the full-length channels. The EAB drives out to the full-length channels. In addition to providing a predictable, row-wide interconnect, this architecture provides increased routing resources. Two neighboring LABs can be connected using a half-row channel, thereby saving the other half of the channel for the other half of the row.

Table 7 summarizes the FastTrack Interconnect routing structure resources available in each FLEX 10KE device.

Table 7. FLEX 10KE FastTrack Interconnect Resources							
Device	Rows	Channels per Row	Columns	Channels per Column			
EPF10K30E	6	216	36	24			
EPF10K50E EPF10K50S	10	216	36	24			
EPF10K100E	12	312	52	24			
EPF10K130E	16	312	52	32			
EPF10K200E EPF10K200S	24	312	52	48			

In addition to general-purpose I/O pins, FLEX 10KE devices have six dedicated input pins that provide low-skew signal distribution across the device. These six inputs can be used for global clock, clear, preset, and peripheral output enable and clock enable control signals. These signals are available as control signals for all LABs and IOEs in the device. The dedicated inputs can also be used as general-purpose data inputs because they can feed the local interconnect of each LAB in the device.

Figure 14 shows the interconnection of adjacent LABs and EABs, with row, column, and local interconnects, as well as the associated cascade and carry chains. Each LAB is labeled according to its location: a letter represents the row and a number represents the column. For example, LAB B3 is in row B, column 3.

On all FLEX 10KE devices (except EPF10K50E and EPF10K200E devices), the input path from the I/O pad to the FastTrack Interconnect has a programmable delay element that can be used to guarantee a zero hold time. EPF10K50S and EPF10K200S devices also support this feature. Depending on the placement of the IOE relative to what it is driving, the designer may choose to turn on the programmable delay to ensure a zero hold time or turn it off to minimize setup time. This feature is used to reduce setup time for complex pin-to-register paths (e.g., PCI designs).

Each IOE selects the clock, clear, clock enable, and output enable controls from a network of I/O control signals called the peripheral control bus. The peripheral control bus uses high-speed drivers to minimize signal skew across the device and provides up to 12 peripheral control signals that can be allocated as follows:

- Up to eight output enable signals
- Up to six clock enable signals
- Up to two clock signals
- Up to two clear signals

If more than six clock enable or eight output enable signals are required, each IOE on the device can be controlled by clock enable and output enable signals driven by specific LEs. In addition to the two clock signals available on the peripheral control bus, each IOE can use one of two dedicated clock pins. Each peripheral control signal can be driven by any of the dedicated input pins or the first LE of each LAB in a particular row. In addition, a LE in a different row can drive a column interconnect, which causes a row interconnect to drive the peripheral control signal. The chipwide reset signal resets all IOE registers, overriding any other control signals.

When a dedicated clock pin drives IOE registers, it can be inverted for all IOEs in the device. All IOEs must use the same sense of the clock. For example, if any IOE uses the inverted clock, all IOEs must use the inverted clock and no IOE can use the non-inverted clock. However, LEs can still use the true or complement of the clock on a LAB-by-LAB basis.

The incoming signal may be inverted at the dedicated clock pin and will drive all IOEs. For the true and complement of a clock to be used to drive IOEs, drive it into both global clock pins. One global clock pin will supply the true, and the other will supply the complement.

When the true and complement of a dedicated input drives IOE clocks, two signals on the peripheral control bus are consumed, one for each sense of the clock.

# Row-to-IOE Connections

When an IOE is used as an input signal, it can drive two separate row channels. The signal is accessible by all LEs within that row. When an IOE is used as an output, the signal is driven by a multiplexer that selects a signal from the row channels. Up to eight IOEs connect to each side of each row channel (see Figure 16).

Figure 16. FLEX 10KE Row-to-IOE Connections

The values for m and n are provided in Table 10.

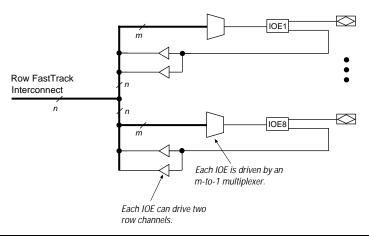


Table 10 lists the FLEX 10KE row-to-IOE interconnect resources.

Table 10. FLEX 10KE Row-to-IOE Interconnect Resources							
Device	Channels per Row (n)	Row Channels per Pin (m)					
EPF10K30E	216	27					
EPF10K50E EPF10K50S	216	27					
EPF10K100E	312	39					
EPF10K130E	312	39					
EPF10K200E EPF10K200S	312	39					

### Column-to-IOE Connections

When an IOE is used as an input, it can drive up to two separate column channels. When an IOE is used as an output, the signal is driven by a multiplexer that selects a signal from the column channels. Two IOEs connect to each side of the column channels. Each IOE can be driven by column channels via a multiplexer. The set of column channels is different for each IOE (see Figure 17).

Figure 17. FLEX 10KE Column-to-IOE Connections

The values for m and n are provided in Table 11.

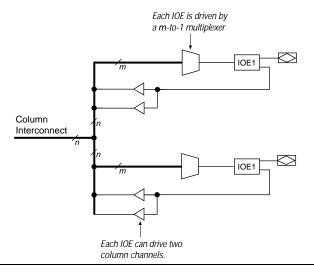


Table 11 lists the FLEX 10KE column-to-IOE interconnect resources.

Table 11. FLEX 10KE Column-to-IOE Interconnect Resources							
Device	Channels per Column (n)	Column Channels per Pin (m)					
EPF10K30E	24	16					
EPF10K50E EPF10K50S	24	16					
EPF10K100E	24	16					
EPF10K130E	32	24					
EPF10K200E EPF10K200S	48	40					

Tables 12 and 13 summarize the ClockLock and ClockBoost parameters for -1 and -2 speed-grade devices, respectively.

Table 12.	Table 12. ClockLock & ClockBoost Parameters for -1 Speed-Grade Devices							
Symbol	Parameter	Condition	Min	Тур	Max	Unit		
$t_R$	Input rise time				5	ns		
t <sub>F</sub>	Input fall time				5	ns		
t <sub>INDUTY</sub>	Input duty cycle		40		60	%		
f <sub>CLK1</sub>	Input clock frequency (ClockBoost clock multiplication factor equals 1)		25		180	MHz		
f <sub>CLK2</sub>	Input clock frequency (ClockBoost clock multiplication factor equals 2)		16		90	MHz		
f <sub>CLKDEV</sub>	Input deviation from user specification in the MAX+PLUS II software (1)				25,000 (2)	PPM		
t <sub>INCLKSTB</sub>	Input clock stability (measured between adjacent clocks)				100	ps		
t <sub>LOCK</sub>	Time required for ClockLock or ClockBoost to acquire lock (3)				10	μs		
t <sub>JITTER</sub>	Jitter on ClockLock or ClockBoost-	$t_{INCLKSTB} < 100$			250	ps		
	generated clock (4)	$t_{INCLKSTB} < 50$			200 (4)	ps		
t <sub>OUTDUTY</sub>	Duty cycle for ClockLock or ClockBoost-generated clock		40	50	60	%		

to Be Driven

Figure 20. FLEX 10KE JTAG Waveforms TMS TDI t<sub>JPSU</sub> TCK t<sub>JPZX</sub> t <sub>JPXZ</sub>  $\mathbf{t}_{\mathsf{JPCO}}$ TDO t<sub>JSH</sub> t<sub>JSSU</sub> Signal to Be Captured t<sub>JSCO</sub>t<sub>JSZX</sub> t<sub>JSXZ</sub> Signal

Figure 20 shows the timing requirements for the JTAG signals.

Table 18 shows the timing parameters and values for FLEX 10KE devices.

Table 18. FLEX 10KE JTAG Timing Parameters & Values							
Symbol	Parameter	Min	Max	Unit			
t <sub>JCP</sub>	TCK clock period	100		ns			
t <sub>JCH</sub>	TCK clock high time	50		ns			
t <sub>JCL</sub>	TCK clock low time	50		ns			
t <sub>JPSU</sub>	JTAG port setup time	20		ns			
t <sub>JPH</sub>	JTAG port hold time	45		ns			
t <sub>JPCO</sub>	JTAG port clock to output		25	ns			
t <sub>JPZX</sub>	JTAG port high impedance to valid output		25	ns			
t <sub>JPXZ</sub>	JTAG port valid output to high impedance		25	ns			
t <sub>JSSU</sub>	Capture register setup time	20		ns			
t <sub>JSH</sub>	Capture register hold time	45		ns			
t <sub>JSCO</sub>	Update register clock to output		35	ns			
t <sub>JSZX</sub>	Update register high impedance to valid output		35	ns			
t <sub>JSXZ</sub>	Update register valid output to high impedance		35	ns			

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>IH</sub>	High-level input voltage		1.7, 0.5 × V <sub>CCIO</sub> (8)		5.75	V
V <sub>IL</sub>	Low-level input voltage		-0.5		0.8, 0.3 × V <sub>CCIO</sub> (8)	V
V <sub>OH</sub>	3.3-V high-level TTL output voltage	$I_{OH} = -8 \text{ mA DC},$ $V_{CCIO} = 3.00 \text{ V } (9)$	2.4			V
	3.3-V high-level CMOS output voltage	$I_{OH} = -0.1 \text{ mA DC},$ $V_{CCIO} = 3.00 \text{ V } (9)$	V <sub>CCIO</sub> – 0.2			V
	3.3-V high-level PCI output voltage	$I_{OH} = -0.5 \text{ mA DC},$ $V_{CCIO} = 3.00 \text{ to } 3.60 \text{ V } (9)$	0.9 × V <sub>CCIO</sub>			V
	2.5-V high-level output voltage	$I_{OH} = -0.1 \text{ mA DC},$ $V_{CCIO} = 2.30 \text{ V } (9)$	2.1			V
		$I_{OH} = -1 \text{ mA DC},$ $V_{CCIO} = 2.30 \text{ V } (9)$	2.0			V
		$I_{OH} = -2 \text{ mA DC},$ $V_{CCIO} = 2.30 \text{ V } (9)$	1.7			V
V <sub>OL</sub>	3.3-V low-level TTL output voltage	I <sub>OL</sub> = 12 mA DC, V <sub>CCIO</sub> = 3.00 V (10)			0.45	V
	3.3-V low-level CMOS output voltage	I <sub>OL</sub> = 0.1 mA DC, V <sub>CCIO</sub> = 3.00 V (10)			0.2	V
	3.3-V low-level PCI output voltage	I <sub>OL</sub> = 1.5 mA DC, V <sub>CCIO</sub> = 3.00 to 3.60 V (10)			0.1 × V <sub>CCIO</sub>	V
	2.5-V low-level output voltage	I <sub>OL</sub> = 0.1 mA DC, V <sub>CCIO</sub> = 2.30 V (10)			0.2	V
		I <sub>OL</sub> = 1 mA DC, V <sub>CCIO</sub> = 2.30 V (10)			0.4	V
		I <sub>OL</sub> = 2 mA DC, V <sub>CCIO</sub> = 2.30 V (10)			0.7	V
I <sub>I</sub>	Input pin leakage current	$V_I = V_{CCIOmax}$ to 0 V (11)	-10		10	μA
I <sub>OZ</sub>	Tri-stated I/O pin leakage current	$V_O = V_{CCIOmax}$ to 0 V (11)	-10		10	μA
I <sub>CC0</sub>	V <sub>CC</sub> supply current (standby)	V <sub>I</sub> = ground, no load, no toggling inputs		5		mA
		V <sub>I</sub> = ground, no load, no toggling inputs (12)		10		mA
R <sub>CONF</sub>	Value of I/O pin pull-	V <sub>CCIO</sub> = 3.0 V (13)	20		50	k¾
	up resistor before and during configuration	V <sub>CCIO</sub> = 2.3 V (13)	30		80	k¾

Table 23. FLEX 10KE Device Capacitance Note (14)							
Symbol	Parameter	Conditions	Min	Max	Unit		
C <sub>IN</sub>	Input capacitance	V <sub>IN</sub> = 0 V, f = 1.0 MHz		10	pF		
C <sub>INCLK</sub>	Input capacitance on dedicated clock pin	V <sub>IN</sub> = 0 V, f = 1.0 MHz		12	pF		
C <sub>OUT</sub>	Output capacitance	V <sub>OUT</sub> = 0 V, f = 1.0 MHz		10	pF		

#### Notes to tables:

- (1) See the Operating Requirements for Altera Devices Data Sheet.
- (2) Minimum DC input voltage is -0.5 V. During transitions, the inputs may undershoot to -2.0 V for input currents less than 100 mA and periods shorter than 20 ns.
- (3) Numbers in parentheses are for industrial-temperature-range devices.
- (4) Maximum  $V_{CC}$  rise time is 100 ms, and  $V_{CC}$  must rise monotonically.
- (5) All pins, including dedicated inputs, clock, I/O, and JTAG pins, may be driven before V<sub>CCINT</sub> and V<sub>CCIO</sub> are powered.
- (6) Typical values are for  $T_A = 25^{\circ}$  C,  $V_{CCINT} = 2.5$  V, and  $V_{CCIO} = 2.5$  V or 3.3 V.
- (7) These values are specified under the FLEX 10KE Recommended Operating Conditions shown in Tables 20 and 21.
- (8) The FLEX 10KE input buffers are compatible with 2.5-V, 3.3-V (LVTTL and LVCMOS), and 5.0-V TTL and CMOS signals. Additionally, the input buffers are 3.3-V PCI compliant when V<sub>CCIO</sub> and V<sub>CCINT</sub> meet the relationship shown in Figure 22.
- (9) The I<sub>OH</sub> parameter refers to high-level TTL, PCI, or CMOS output current.
- (10) The  $I_{OL}$  parameter refers to low-level TTL, PCI, or CMOS output current. This parameter applies to open-drain pins as well as output pins.
- (11) This value is specified for normal device operation. The value may vary during power-up.
- (12) This parameter applies to -1 speed-grade commercial-temperature devices and -2 speed-grade-industrial temperature devices.
- (13) Pin pull-up resistance values will be lower if the pin is driven higher than  $V_{CCIO}$  by an external source.
- (14) Capacitance is sample-tested only.

Figure 26. FLEX 10KE Device IOE Timing Model

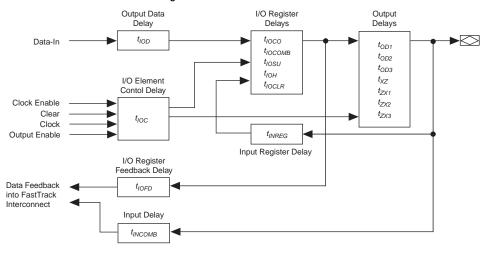


Figure 27. FLEX 10KE Device EAB Timing Model

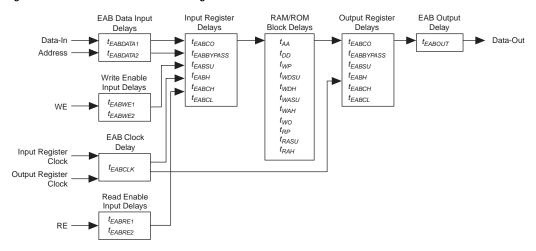


Table 53. EPF10K130E Device IOE Timing Microparameters   Note (1)							
Symbol	-1 Spec	ed Grade	-2 Spee	-2 Speed Grade		d Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>OD3</sub>		4.0		5.6		7.5	ns
$t_{XZ}$		2.8		4.1		5.5	ns
$t_{ZX1}$		2.8		4.1		5.5	ns
$t_{ZX2}$		2.8		4.1		5.5	ns
$t_{ZX3}$		4.0		5.6		7.5	ns
t <sub>INREG</sub>		2.5		3.0		4.1	ns
t <sub>IOFD</sub>		0.4		0.5		0.6	ns
t <sub>INCOMB</sub>		0.4		0.5		0.6	ns

Table 54. EPF10K130E Device EAB Internal Microparameters (Part 1 of 2)         Note (1)							
Symbol	-1 Speed Grade		-2 Spee	-2 Speed Grade		ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>EABDATA1</sub>		1.5		2.0		2.6	ns
t <sub>EABDATA2</sub>		0.0		0.0		0.0	ns
t <sub>EABWE1</sub>		1.5		2.0		2.6	ns
t <sub>EABWE2</sub>		0.3		0.4		0.5	ns
t <sub>EABRE1</sub>		0.3		0.4		0.5	ns
t <sub>EABRE2</sub>		0.0		0.0		0.0	ns
t <sub>EABCLK</sub>		0.0		0.0		0.0	ns
t <sub>EABCO</sub>		0.3		0.4		0.5	ns
t <sub>EABBYPASS</sub>		0.1		0.1		0.2	ns
t <sub>EABSU</sub>	0.8		1.0		1.4		ns
t <sub>EABH</sub>	0.1		0.2		0.2		ns
t <sub>EABCLR</sub>	0.3		0.4		0.5		ns
$t_{AA}$		4.0		5.0		6.6	ns
$t_{WP}$	2.7		3.5		4.7		ns
t <sub>RP</sub>	1.0		1.3		1.7		ns
t <sub>WDSU</sub>	1.0		1.3		1.7		ns
$t_{WDH}$	0.2		0.2		0.3		ns
t <sub>WASU</sub>	1.6		2.1		2.8		ns
t <sub>WAH</sub>	1.6		2.1		2.8		ns
t <sub>RASU</sub>	3.0		3.9		5.2		ns
t <sub>RAH</sub>	0.1		0.1		0.2		ns
$t_{WO}$		1.5		2.0		2.6	ns

Table 74. EPF10K200S Device IOE Timing Microparameters (Part 2 of 2) Note (1)									
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit		
	Min	Max	Min	Max	Min	Max			
$t_{ZX2}$		4.5		4.8		6.6	ns		
$t_{ZX3}$		6.6		7.6		10.1	ns		
t <sub>INREG</sub>		3.7		5.7		7.7	ns		
t <sub>IOFD</sub>		1.8		3.4		4.0	ns		
t <sub>INCOMB</sub>		1.8		3.4		4.0	ns		

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t <sub>EABDATA1</sub>		1.8		2.4		3.2	ns
t <sub>EABDATA1</sub>		0.4		0.5		0.6	ns
t <sub>EABWE1</sub>		1.1		1.7		2.3	ns
t <sub>EABWE2</sub>		0.0		0.0		0.0	ns
t <sub>EABRE1</sub>		0		0		0	ns
t <sub>EABRE2</sub>		0.4		0.5		0.6	ns
t <sub>EABCLK</sub>		0.0		0.0		0.0	ns
t <sub>EABCO</sub>		0.8		0.9		1.2	ns
t <sub>EABBYPASS</sub>		0.0		0.1		0.1	ns
t <sub>EABSU</sub>	0.7		1.1		1.5		ns
t <sub>EABH</sub>	0.4		0.5		0.6		ns
t <sub>EABCLR</sub>	0.8		0.9		1.2		ns
t <sub>AA</sub>		2.1		3.7		4.9	ns
$t_{WP}$	2.1		4.0		5.3		ns
t <sub>RP</sub>	1.1		1.1		1.5		ns
t <sub>WDSU</sub>	0.5		1.1		1.5		ns
t <sub>WDH</sub>	0.1		0.1		0.1		ns
t <sub>WASU</sub>	1.1		1.6		2.1		ns
t <sub>WAH</sub>	1.6		2.5		3.3		ns
t <sub>RASU</sub>	1.6		2.6		3.5		ns
t <sub>RAH</sub>	0.1		0.1		0.2		ns
t <sub>wo</sub>		2.0		2.4		3.2	ns
t <sub>DD</sub>		2.0		2.4		3.2	ns
t <sub>EABOUT</sub>		0.0		0.1		0.1	ns
t <sub>EABCH</sub>	1.5		2.0		2.5		ns
t <sub>EABCL</sub>	2.1		2.8		3.8		ns

# Power Consumption

The supply power (P) for FLEX 10KE devices can be calculated with the following equation:

$$P = P_{INT} + P_{IO} = (I_{CCSTANDBY} + I_{CCACTIVE}) \times V_{CC} + P_{IO}$$

The  $I_{CCACTIVE}$  value depends on the switching frequency and the application logic. This value is calculated based on the amount of current that each LE typically consumes. The  $P_{IO}$  value, which depends on the device output load characteristics and switching frequency, can be calculated using the guidelines given in *Application Note 74 (Evaluating Power for Altera Devices)*.

Compared to the rest of the device, the embedded array consumes a negligible amount of power. Therefore, the embedded array can be ignored when calculating supply current.

The I<sub>CCACTIVE</sub> value can be calculated with the following equation:

$$I_{CCACTIVE} = K \times f_{\boldsymbol{MAX}} \times N \times \boldsymbol{tog_{LC}} \times \frac{\mu A}{MHz \times LE}$$

Where:

**f**<sub>MAX</sub> = Maximum operating frequency in MHz N = Total number of LEs used in the device

togLC = Average percent of LEs toggling at each clock

(typically 12.5%)

K = Constant

Table 80 provides the constant (K) values for FLEX 10KE devices.

Table 80. FLEX 10KE K Constant Values				
Device	K Value			
EPF10K30E	4.5			
EPF10K50E	4.8			
EPF10K50S	4.5			
EPF10K100E	4.5			
EPF10K130E	4.6			
EPF10K200E	4.8			
EPF10K200S	4.6			

This calculation provides an  $I_{CC}$  estimate based on typical conditions with no output load. The actual  $I_{CC}$  should be verified during operation because this measurement is sensitive to the actual pattern in the device and the environmental operating conditions.